

FEATURES

Latch-up immune under all circumstances
 Human body model (HBM) ESD rating: 8 kV
 Low on resistance: 13.5 Ω
 ± 9 V to ± 22 V dual-supply operation
 9 V to 40 V single-supply operation
 48 V supply maximum ratings
 Fully specified at ± 15 V, ± 20 V, $+12$ V, and $+36$ V
 V_{DD} to V_{SS} analog signal range

APPLICATIONS

High voltage signal routing
 Automatic test equipment
 Analog front-end circuits
 Precision data acquisition
 Industrial instrumentation
 Amplifier gain select
 Relay replacement

GENERAL DESCRIPTION

The **ADG5421/ADG5423** are monolithic industrial, complementary metal oxide semiconductor (CMOS) analog switches containing two independent latch-up immune single-pole/single-throw (SPST) switches. Each switch conducts equally well in both directions when on, and has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked. Both **ADG5421** switches are turned on with a Logic 1 input, whereas the **ADG5423** has one switch turned on and one switch turned off for a Logic 1 input. The **ADG5423** exhibits break-before-make action for use in multiplexer applications.

The ultralow on resistance and on-resistance flatness of these switches make them ideal solutions for data acquisition and gain switching applications where low distortion is critical. The latch-up immune construction and high ESD rating make these switches more robust in harsh environments.

FUNCTIONAL BLOCK DIAGRAMS

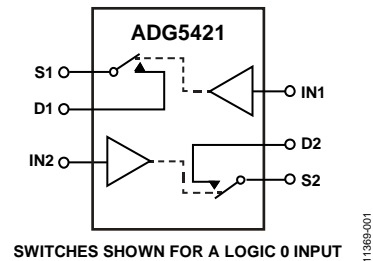


Figure 1. **ADG5421**

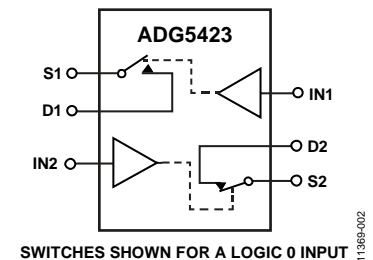


Figure 2. **ADG5423**

PRODUCT HIGHLIGHTS

1. Trench isolation guards against latch-up. A dielectric trench separates the P channel and N channel transistors, thereby preventing latch-up even under severe overvoltage conditions.
2. Low R_{ON} of 13.5 Ω .
3. Dual-supply operation. For applications where the analog signal is bipolar, the **ADG5421/ADG5423** can operate from dual supplies up to ± 22 V.
4. Single-supply operation. For applications where the analog signal is unipolar, the **ADG5421/ADG5423** can operate from a single-rail power supply up to 40 V.
5. 3 V logic compatible digital inputs: $V_{INH} = 2.0$ V, $V_{INL} = 0.8$ V.
6. No V_L logic power supply required.
7. Available in 10-lead MSOP and 10-lead 3 mm \times 3 mm LFCSP packages.

Rev. A

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TABLE OF CONTENTS

Features	1	Continuous Current per Channel, Sx or Dx.....	7
Applications.....	1	Absolute Maximum Ratings	8
Functional Block Diagrams.....	1	ESD Caution.....	8
General Description	1	Pin Configurations and Function Descriptions	9
Product Highlights	1	Typical Performance Characteristics	10
Revision History	2	Test Circuits.....	13
Specifications.....	3	Terminology	15
±15 V Dual Supply	3	Applications Information	16
±20 V Dual Supply	4	Trench Isolation.....	16
12 V Single Supply.....	5	Outline Dimensions	17
36 V Single Supply.....	6	Ordering Guide	17

REVISION HISTORY

1/15—Rev. 0 to Rev. A

Added 10-Lead LFCSP Package.....	Universal
Changes to Table 5.....	7
Added Figure 3, Renumbered Sequentially; Changes to Table 7.....	9
Changes to Figure 5.....	10
Changes to Figure 30.....	14
Updated Outline Dimensions	17
Changes to Ordering Guide	17

9/13—Revision 0: Initial Version

SPECIFICATIONS

±15 V DUAL SUPPLY

$V_{DD} = +15\text{ V} \pm 10\%$, $V_{SS} = -15\text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted.

Table 1.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V _{DD} to V _{SS}	V	V _S = ±10 V, I _S = −10 mA; see Figure 25 V _{DD} = +13.5 V, V _{SS} = −13.5 V V _S = ±10 V, I _S = −10 mA
On Resistance, R _{ON}	13.5	19	23	Ω typ	
	15			Ω max	
On-Resistance Match Between Channels, ΔR _{ON}	0.1			Ω typ	
	0.8	1.3	1.4	Ω max	V _S = ±10 V, I _S = −10 mA
On-Resistance Flatness, R _{FLAT (ON)}	1.8			Ω typ	
	2.2	2.7	3.1	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.05	±1	±10	nA typ	V _{DD} = +16.5 V, V _{SS} = −16.5 V V _S = ±10 V, V _D = ∓ 10 V; see Figure 24
	±0.25			nA max	
Drain Off Leakage, I _D (Off)	±0.05	±1	±10	nA typ	V _S = ±10 V, V _D = ∓ 10 V; see Figure 24
	±0.25			nA max	
Channel On Leakage, I _D (On), I _S (On)	±0.1	±4	±20	nA typ	V _S = V _D = ±10 V; see Figure 23
	±0.4			nA max	
DIGITAL INPUTS					
Input High Voltage, V _{INH}	0.002		2.0	V min	V _{IN} = V _{GND} Or V _{DD}
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}			±0.1	μA typ	
		μA max			
Digital Input Capacitance, C _{IN}	6			pF typ	
DYNAMIC CHARACTERISTICS ¹					
t _{ON}	185	273	313	ns typ	R _L = 300 Ω, C _L = 35 pF V _S = 10 V; see Figure 30
	220			ns max	
t _{OFF}	163	219	242	ns typ	R _L = 300 Ω, C _L = 35 pF V _S = 10 V; see Figure 30
	196			ns max	
Break-Before-Make Time Delay, t _D (ADG5423 Only)	73			ns typ	R _L = 300 Ω, C _L = 35 pF
			21	ns min	V _{S1} = V _{S2} = 10 V; see Figure 32
Charge Injection, Q _{INJ}	95			pC typ	V _S = 0 V, R _S = 0 Ω, C _L = 1 nF; see Figure 31
Off Isolation	−55			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 26
Channel-to-Channel Crosstalk	−85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 29
Total Harmonic Distortion + Noise	0.01			% typ	R _L = 1 kΩ, 15 V p-p, f = 20 Hz to 20 kHz; see Figure 27
−3 dB Bandwidth	250			MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 28
Insertion Loss	−1			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 28
C _S (Off)	12			pF typ	V _S = 0 V, f = 1 MHz
C _D (Off)	13			pF typ	V _S = 0 V, f = 1 MHz
C _D (On), C _S (On)	44			pF typ	V _S = 0 V, f = 1 MHz
POWER REQUIREMENTS					
I _{DD}	45		70	μA typ	V _{DD} = +16.5 V, V _{SS} = −16.5 V Digital inputs = 0 V or V _{DD}
	55			μA max	
I _{SS}	0.001			μA typ	Digital inputs = 0 V or V _{DD}
				μA max	
V _{DD} /V _{SS}			±9/±22	V min/V max	GND = 0 V

¹ Guaranteed by design; not subject to production test.

±20 V DUAL SUPPLY

$V_{DD} = +20\text{ V} \pm 10\%$, $V_{SS} = -20\text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted.

Table 2.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V _{DD} to V _{SS}	V	V _S = ±15 V, I _S = −10 mA; see Figure 25 V _{DD} = +18 V, V _{SS} = −18 V
On Resistance, R _{ON}	12.5 14	18	22	Ω typ Ω max	
On-Resistance Match Between Channels, ΔR _{ON}	0.1			Ω typ	V _S = ±15 V, I _S = −10 mA
On-Resistance Flatness, R _{FLAT (ON)}	0.8	1.3	1.4	Ω max	V _S = ±15 V, I _S = −10 mA
	2.3			Ω typ	
	2.7	3.3	3.7	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.05 ±0.25	±1	±10	nA typ nA max	V _{DD} = +22 V, V _{SS} = −22 V V _S = ±15 V, V _D = ∓ 15 V; see Figure 24
Drain Off Leakage, I _D (Off)	±0.05 ±0.25	±1	±10	nA typ nA max	V _S = ±15 V, V _D = ∓ 15 V; see Figure 24
Channel On Leakage, I _D (On), I _S (On)	±0.1 ±0.4	±4	±20	nA typ nA max	V _S = V _D = ±15 V; see Figure 23
DIGITAL INPUTS					
Input High Voltage, V _{INH}			2.0	V min	V _{IN} = V _{GND} or V _{DD}
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}	0.002		±0.1	μA typ μA max	
Digital Input Capacitance, C _{IN}	6			pF typ	
DYNAMIC CHARACTERISTICS ¹					
t _{ON}	168			ns typ	R _L = 300 Ω, C _L = 35 pF, V _S = 10 V; see Figure 30
t _{OFF}	199	243	276	ns max	V _S = 10 V; see Figure 30
	156			ns typ	R _L = 300 Ω, C _L = 35 pF
	184	204	218	ns max	V _S = 10 V; see Figure 30
Break-Before-Make Time Delay, t _D (ADG5423 Only)	65		38	ns typ ns min	R _L = 300 Ω, C _L = 35 pF V _{S1} = V _{S2} = 10 V; see Figure 32
Charge Injection, Q _{INJ}	120			pC typ	V _S = 0 V, R _S = 0 Ω, C _L = 1 nF; see Figure 31
Off Isolation	−55			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 26
Channel-to-Channel Crosstalk	−85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 29
Total Harmonic Distortion + Noise	0.01			% typ	R _L = 1 kΩ, 20 V p-p, f = 20 Hz to 20 kHz; see Figure 27
−3 dB Bandwidth	250			MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 28
Insertion Loss	−0.8			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 28
C _S (Off)	11			pF typ	V _S = 0 V, f = 1 MHz
C _D (Off)	12			pF typ	V _S = 0 V, f = 1 MHz
C _D (On), C _S (On)	44			pF typ	V _S = 0 V, f = 1 MHz
POWER REQUIREMENTS					
I _{DD}	50 70		110	μA typ μA max	V _{DD} = +22 V, V _{SS} = −22 V Digital inputs = 0 V or V _{DD}
I _{SS}	0.001		1	μA typ μA max	Digital inputs = 0 V or V _{DD}
V _{DD} /V _{SS}			±9/±22	V min/V max	GND = 0 V

¹ Guaranteed by design; not subject to production test.

12 V SINGLE SUPPLY

$V_{DD} = 12\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 3.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V _{DD}	V	
On Resistance, R _{ON}	26			Ω typ	V _S = 0 V to 10 V, I _S = −10 mA; see Figure 25
On-Resistance Match Between Channels, ΔR _{ON}	30 0.1	38	44	Ω max Ω typ	V _{DD} = 10.8 V, V _{SS} = 0 V V _S = 0 V to 10 V, I _S = −10 mA
On-Resistance Flatness, R _{FLAT (ON)}	1 5.5 6.8	1.5 8.3	1.6 12.3	Ω max Ω typ Ω max	V _S = 0 V to 10 V, I _S = −10 mA
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.05			nA typ	V _{DD} = +13.2 V, V _{SS} = 0 V V _S = 1 V to 10 V, V _D = 10 V to 1 V; see Figure 24
Drain Off Leakage, I _D (Off)	±0.25 ±0.05	±1	±10	nA max nA typ	V _S = 1 V to 10 V, V _D = 10 V to 1 V; see Figure 24
Channel On Leakage, I _D (On), I _S (On)	±0.25 ±0.1 ±0.4	±1 ±4	±10 ±20	nA max nA typ nA max	V _S = V _D = 1 V to 10 V; see Figure 23
DIGITAL INPUTS					
Input High Voltage, V _{INH}			2.0	V min	V _{IN} = V _{GND} or V _{DD}
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}	0.002		±0.1	μA typ μA max	
Digital Input Capacitance, C _{IN}	6			pF typ	
DYNAMIC CHARACTERISTICS ¹					
t _{ON}	295 370	470	540	ns typ ns max	R _L = 300 Ω, C _L = 35 pF V _S = 8 V; see Figure 30
t _{OFF}	192 235	273	295	ns typ ns max	R _L = 300 Ω, C _L = 35 pF V _S = 8 V; see Figure 30
Break-Before-Make Time Delay, t _D (ADG5423 Only)	142		78	ns typ	R _L = 300 Ω, C _L = 35 pF
Charge Injection, Q _{INJ}	55			ns min pC typ	V _{S1} = V _{S2} = 8 V; see Figure 32 V _S = 6 V, R _S = 0 Ω, C _L = 1 nF; see Figure 31
Off Isolation	−55			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 26
Channel-to-Channel Crosstalk	−85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 29
Total Harmonic Distortion + Noise	0.03			% typ	R _L = 1 kΩ, 6 V p-p, f = 20 Hz to 20 kHz; see Figure 27
−3 dB Bandwidth	290			MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 28
Insertion Loss	−1.7			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 28
C _S (Off)	14			pF typ	V _S = 6 V, f = 1 MHz
C _D (Off)	15			pF typ	V _S = 6 V, f = 1 MHz
C _D (On), C _S (On)	38			pF typ	V _S = 6 V, f = 1 MHz
POWER REQUIREMENTS					
I _{DD}	40 50		65 9/40	μA typ μA max V min/V max	V _{DD} = 13.2 V Digital inputs = 0 V or V _{DD}
V _{DD}					GND = 0 V, V _{SS} = 0 V

¹ Guaranteed by design; not subject to production test.

36 V SINGLE SUPPLY

$V_{DD} = 36\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 4.

Parameter	25°C	−40°C to +85°C	−40°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 V to V _{DD}	V	
On Resistance, R _{ON}	14.5 16	20	24	Ω typ Ω max	V _S = 0 V to 30 V, I _S = −10 mA; see Figure 25 V _{DD} = 32.4 V, V _{SS} = 0 V
On-Resistance Match Between Channels, ΔR _{ON}	0.1			Ω typ	V _S = 0 V to 30 V, I _S = −10 mA
	0.8	1.3	1.4	Ω max	
On-Resistance Flatness, R _{FLAT (ON)}	3.5 4.3		6.5	Ω typ Ω max	V _S = 0 V to 30 V, I _S = −10 mA
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.05			nA typ	V _{DD} = 39.6 V, V _{SS} = 0 V V _S = 1 V to 30 V, V _D = 30 V to 1 V; see Figure 24
Drain Off Leakage, I _D (Off)	±0.25 ±0.05	±1	±10	nA max nA typ	V _S = 1 V to 30 V, V _D = 30 V to 1 V; see Figure 24
Channel On Leakage, I _D (On), I _S (On)	±0.25 ±0.1 ±0.4	±1 ±4	±10 ±20	nA max nA typ nA max	V _S = V _D = 1 V to 30 V; see Figure 23
DIGITAL INPUTS					
Input High Voltage, V _{INH}			2.0	V min	
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}	0.002		±0.1	μA typ μA max	V _{IN} = V _{GND} or V _{DD}
Digital Input Capacitance, C _{IN}	6			pF typ	
DYNAMIC CHARACTERISTICS ¹					
t _{ON}	181 210	245	280	ns typ ns max	R _L = 300 Ω, C _L = 35 pF V _S = 18 V; see Figure 30
t _{OFF}	170 192	205	220	ns typ ns max	R _L = 300 Ω, C _L = 35 pF V _S = 18 V; see Figure 30
Break-Before-Make Time Delay, t _D (ADG5423 Only)	66		37	ns typ	R _L = 300 Ω, C _L = 35 pF
Charge Injection, Q _{INJ}	110			ns min	V _{S1} = V _{S2} = 18 V; see Figure 32
Off Isolation	−55			pC typ	V _S = 18 V, R _S = 0 Ω, C _L = 1 nF; see Figure 31
Channel-to-Channel Crosstalk	−85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 26
Total Harmonic Distortion + Noise	0.01			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 29
				% typ	R _L = 1 kΩ, 18 V p-p, f = 20 Hz to 20 kHz; see Figure 27
−3 dB Bandwidth	260			MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 28
Insertion Loss	−0.9			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 28
C _S (Off)	13			pF typ	V _S = 18 V, f = 1 MHz
C _D (Off)	16			pF typ	V _S = 18 V, f = 1 MHz
C _D (On), C _S (On)	38			pF typ	V _S = 18 V, f = 1 MHz
POWER REQUIREMENTS					
I _{DD}	80 100		130	μA typ μA max	V _{DD} = 39.6 V Digital inputs = 0 V or V _{DD}
V _{DD}			9/40	V min/V max	GND = 0 V, V _{SS} = 0 V

¹ Guaranteed by design; not subject to production test.

CONTINUOUS CURRENT PER CHANNEL, Sx OR Dx

Table 5.

Parameter	25°C	85°C	125°C	Unit	Test Conditions/Comments
CONTINUOUS CURRENT, Sx OR Dx					$\theta_{JA} = 133.1^{\circ}\text{C/W}$
10-Lead MSOP					
$V_{DD} = +15\text{ V}, V_{SS} = -15\text{ V}$	84	58	39	mA maximum	
$V_{DD} = +20\text{ V}, V_{SS} = -20\text{ V}$	89	60	41	mA maximum	
$V_{DD} = 12\text{ V}, V_{SS} = 0\text{ V}$	67	47	32	mA maximum	
$V_{DD} = 36\text{ V}, V_{SS} = 0\text{ V}$	87	59	40	mA maximum	
10-Lead LFCSP					$\theta_{JA} = 48.7^{\circ}\text{C/W}$
$V_{DD} = +15\text{ V}, V_{SS} = -15\text{ V}$	129	80	48	mA maximum	
$V_{DD} = +20\text{ V}, V_{SS} = -20\text{ V}$	135	83	50	mA maximum	
$V_{DD} = 12\text{ V}, V_{SS} = 0\text{ V}$	103	37	43	mA maximum	
$V_{DD} = 36\text{ V}, V_{SS} = 0\text{ V}$	132	82	49	mA maximum	

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 6.

Parameter	Rating
V_{DD} to V_{SS}	48 V
V_{DD} to GND	−0.3 V to +48 V
V_{SS} to GND	+0.3 V to −48 V
Analog Inputs ¹	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Digital Inputs ¹	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Peak Current, Sx or Dx Pins	300 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous Current, Sx or Dx ²	Data + 15%
Temperature Range	
Operating	−40°C to +125°C
Storage	−65°C to +150°C
Junction Temperature	150°C
Thermal Impedance, θ_{JA}	
10-Lead MSOP (4-Layer Board)	133.1°C/W
10-Lead LFCSP	48.7°C/W
Reflow Soldering Peak Temperature, Pb Free	As per JEDEC J-STD-020
Human Body Model (HBM) ESD	8 kV

¹ Overvoltages at the INx, Sx, and Dx pins are clamped by internal diodes. Limit current to the maximum ratings given.

² See Table 5.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

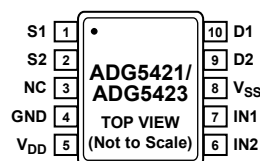
Only one absolute maximum rating can be applied at any one time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

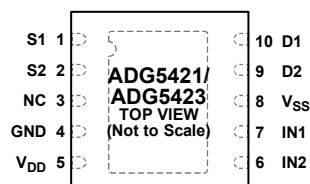


NOTES

1. NC = NO CONNECT. NOT INTERNALLY CONNECTED.

Figure 3. MSOP Pin Configuration

11369-033



NOTES

1. NC = NO CONNECT. DO NOT CONNECT TO THIS PIN.
2. EXPOSED PAD TIED TO SUBSTRATE, V_{SS} .

Figure 4. LFCSP Pin Configuration

11369-033

Table 7. Pin Function Descriptions

MSOP Pin No. ¹	LFCSP Pin No.	Mnemonic	Description
1	1	S1	Source Terminal 1. This pin can be an input or output.
2	2	S2	Source Terminal 2. This pin can be an input or output.
3	3	NC	No Connect. Not internally connected.
4	4	GND	Ground (0 V) Reference.
5	5	V_{DD}	Most Positive Power Supply Potential.
6	6	IN2	Logic Control Input.
7	7	IN1	Logic Control Input.
8	8	V_{SS}	Most Negative Power Supply Potential.
9	9	D2	Drain Terminal 2. This pin can be an input or output.
10	10	D1	Drain Terminal 1. This pin can be an input or output.
N/A	EPAD		Exposed Pad. The exposed pad is tied to substrate, V_{SS} .

¹ N/A means not applicable.

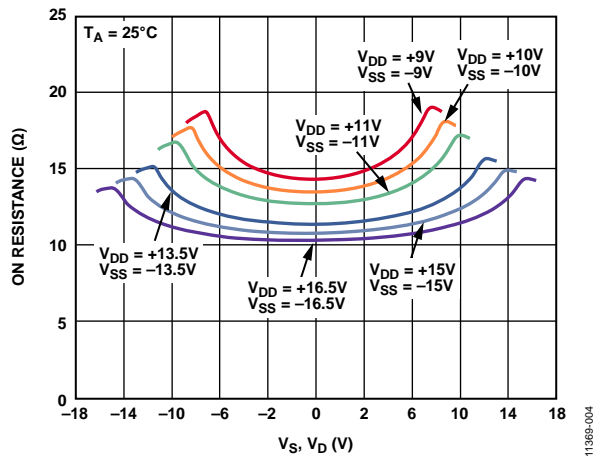
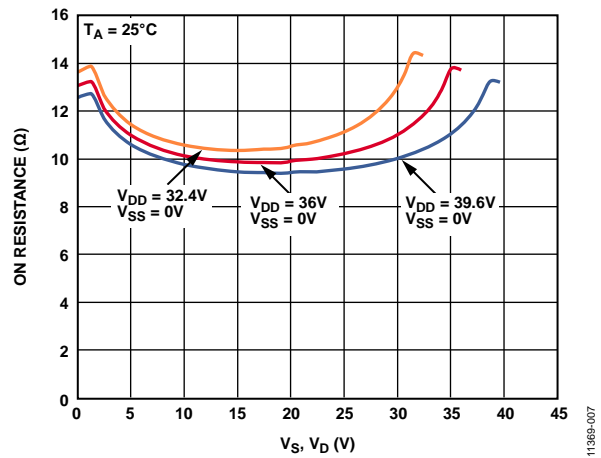
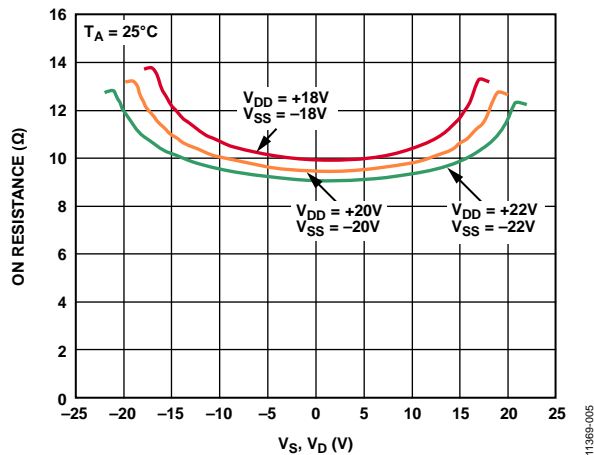
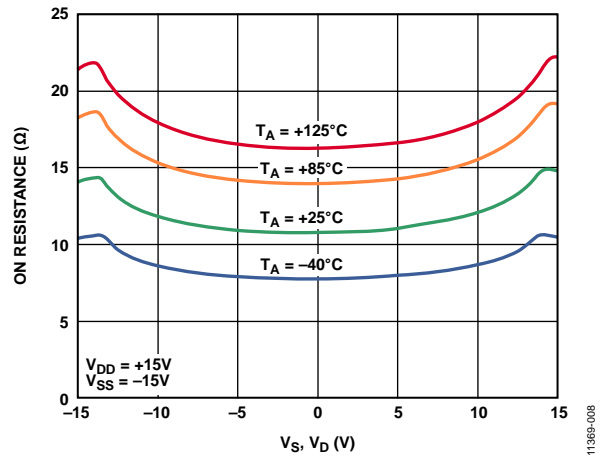
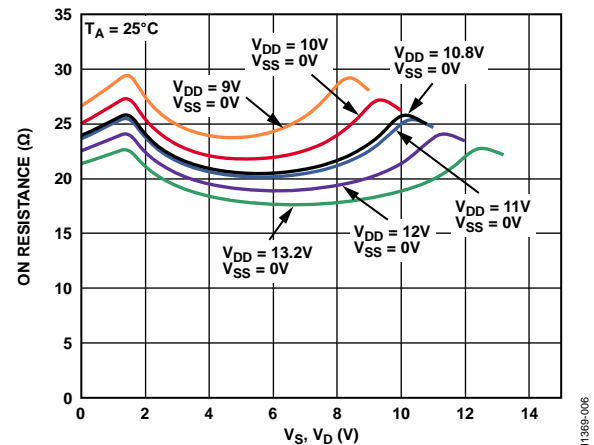
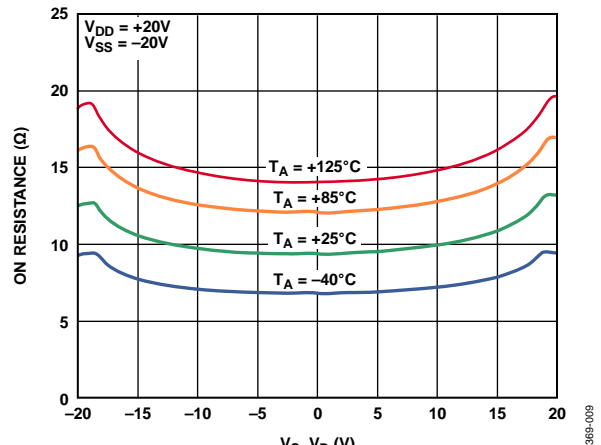
Table 8. ADG5421 Truth Table

INx	Switch Conditions
0	Off
1	On

Table 9. ADG5423 Truth Table

INx	Switch 1 Condition	Switch 2 Condition
0	Off	On
1	On	Off

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 5. On Resistance as a Function of V_S , V_D (Dual Supply: ± 10 V, ± 15 V)Figure 8. On Resistance as a Function of V_S , V_D (Single Supply: 36 V)Figure 6. On Resistance as a Function of V_S , V_D (Dual Supply: ± 20 V)Figure 9. On Resistance as a Function of V_S (V_D) for Different Temperatures, ± 15 V Dual SupplyFigure 7. On Resistance as a Function of V_S , V_D (Single Supply: 10 V, 12 V)Figure 10. On Resistance as a Function of V_S (V_D) for Different Temperatures, ± 20 V Dual Supply

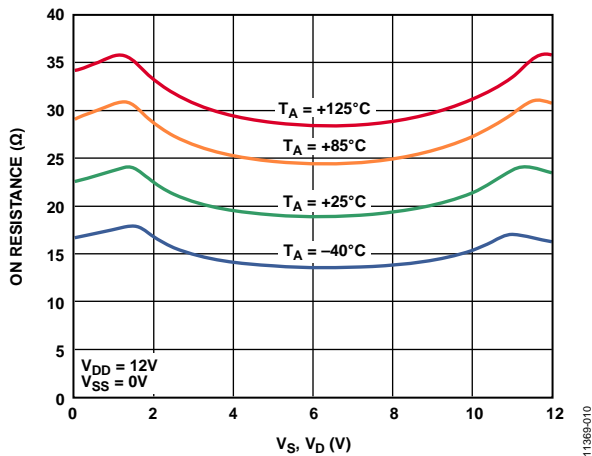


Figure 11. On Resistance as a Function of V_S (V_D) for Different Temperatures, 12 V Single Supply

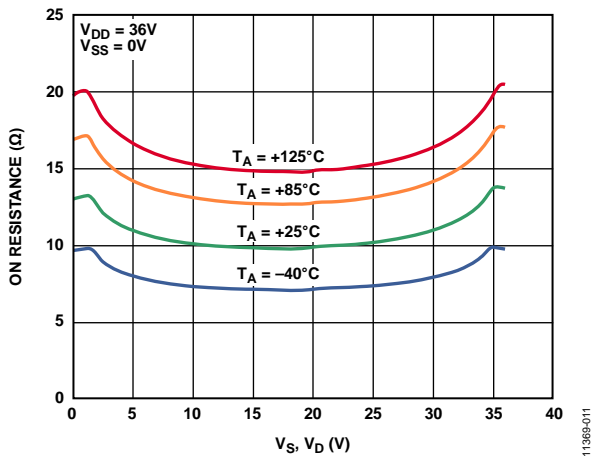


Figure 12. On Resistance as a Function of V_S (V_D) for Different Temperatures, 36 V Single Supply

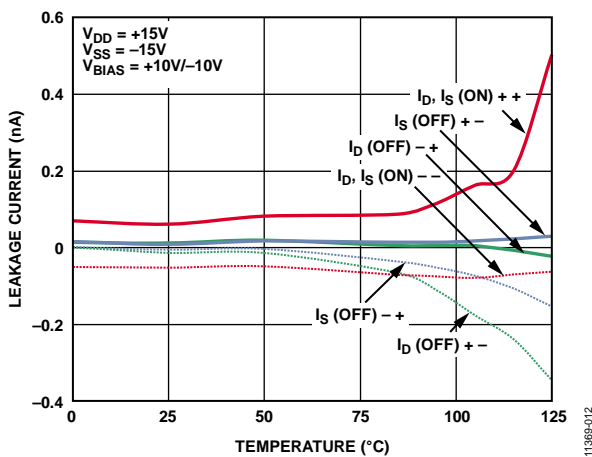


Figure 13. Leakage Currents as a Function of Temperature, ± 15 V Dual Supply

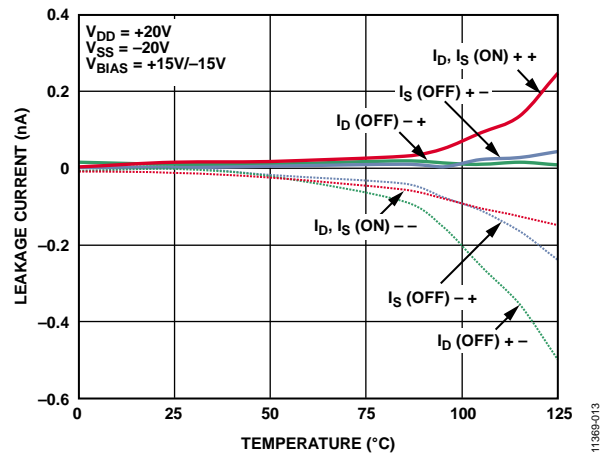


Figure 14. Leakage Currents as a Function of Temperature, ± 20 V Dual Supply

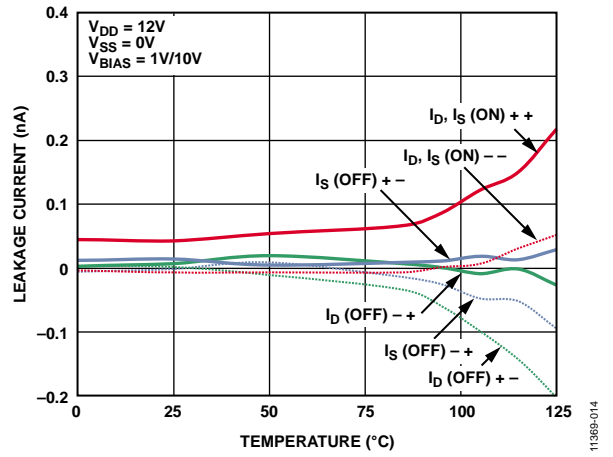


Figure 15. Leakage Currents as a Function of Temperature, 12 V Single Supply

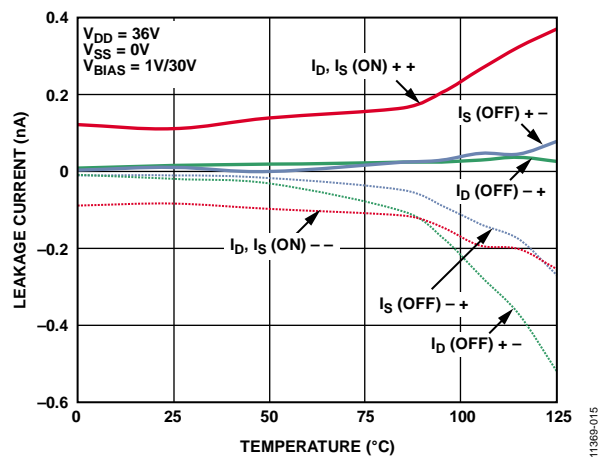


Figure 16. Leakage Currents as a Function of Temperature, 36 V Single Supply

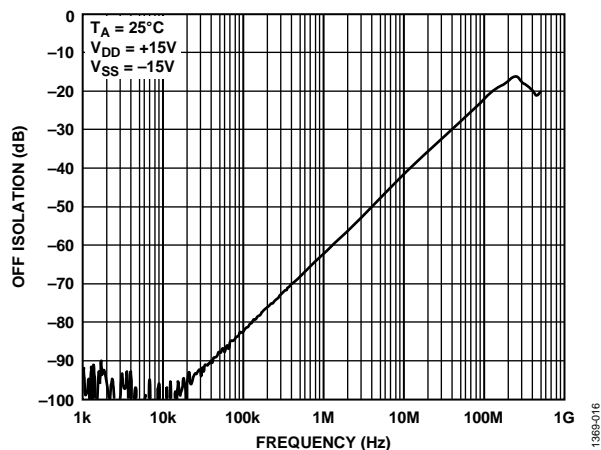


Figure 17. Off Isolation vs. Frequency

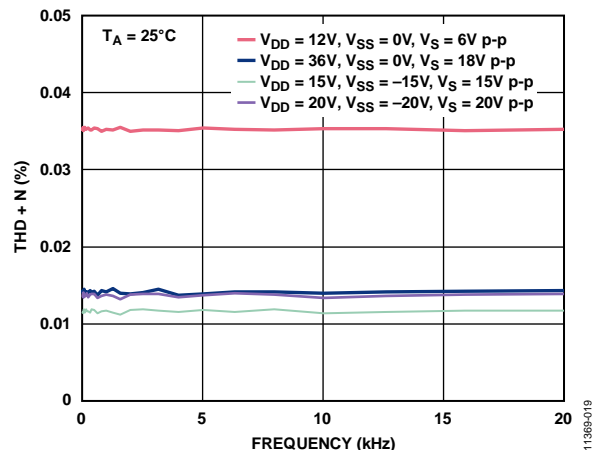


Figure 20. THD + N vs. Frequency

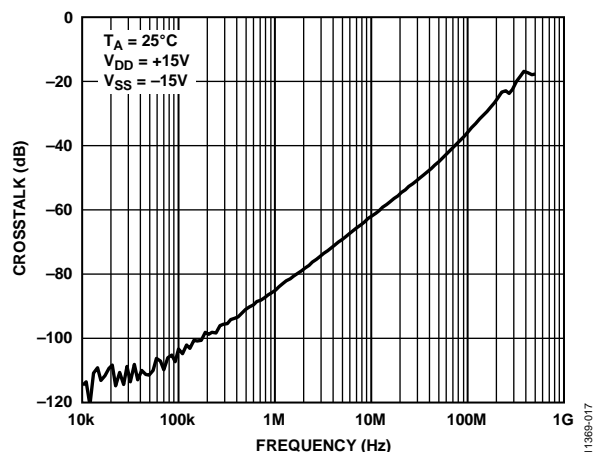


Figure 18. Crosstalk vs. Frequency

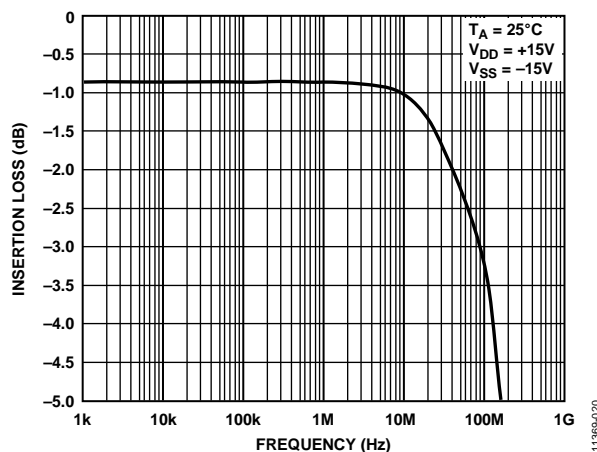


Figure 21. Bandwidth

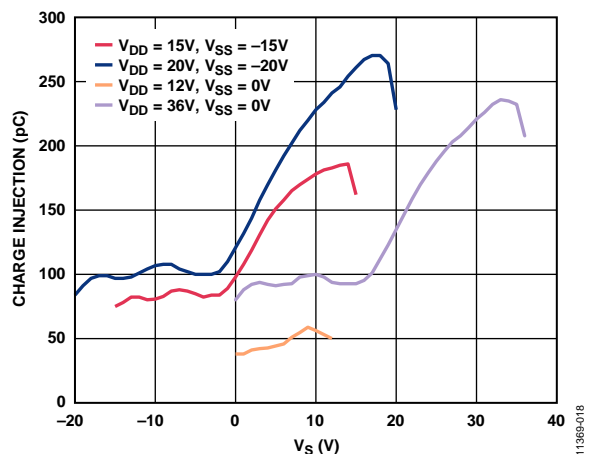


Figure 19. Charge Injection vs. Source Voltage (V_S)

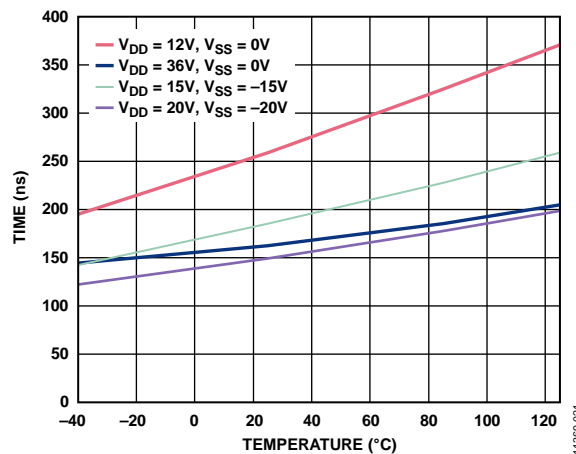


Figure 22. $t_{\text{TRANSITION}}$ Times vs. Temperature

TEST CIRCUITS

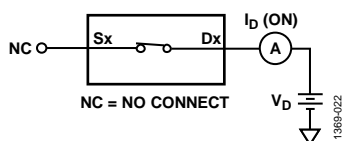


Figure 23. On Leakage

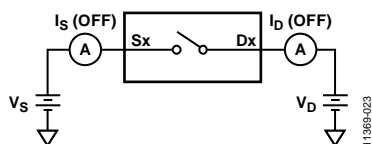


Figure 24. Off Leakage

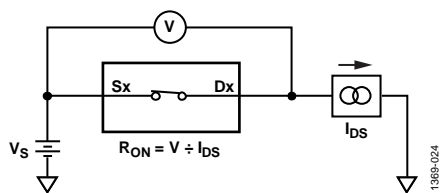


Figure 25. On Resistance

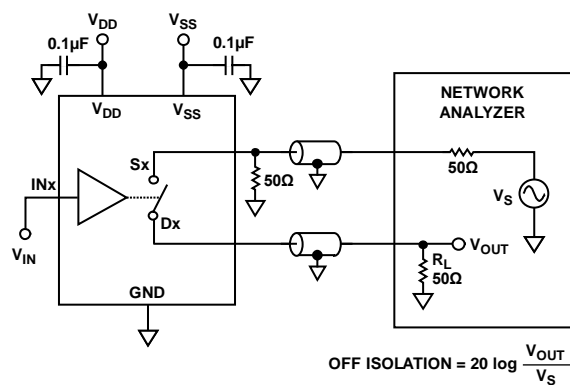


Figure 26. Off Isolation

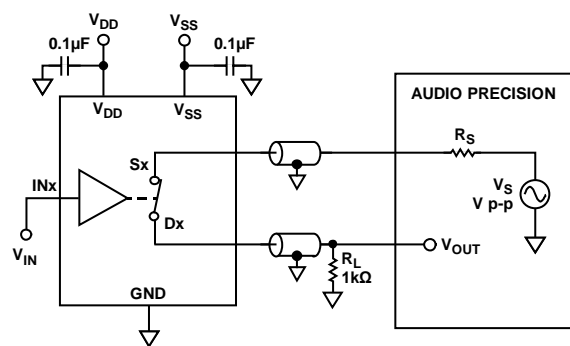


Figure 27. THD + Noise

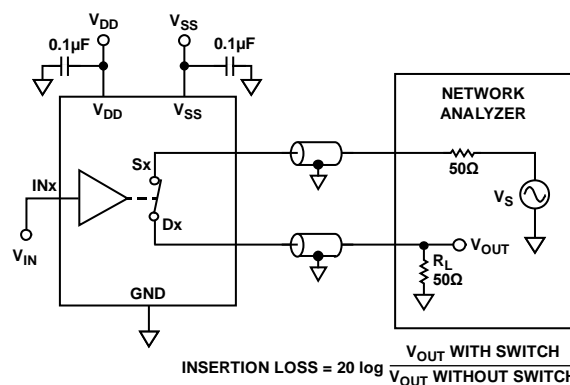


Figure 28. Bandwidth

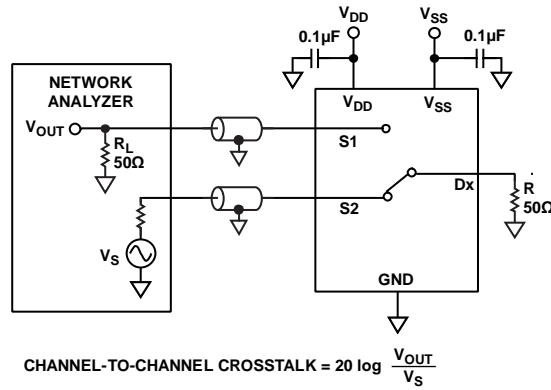


Figure 29. Channel-to-Channel Crosstalk

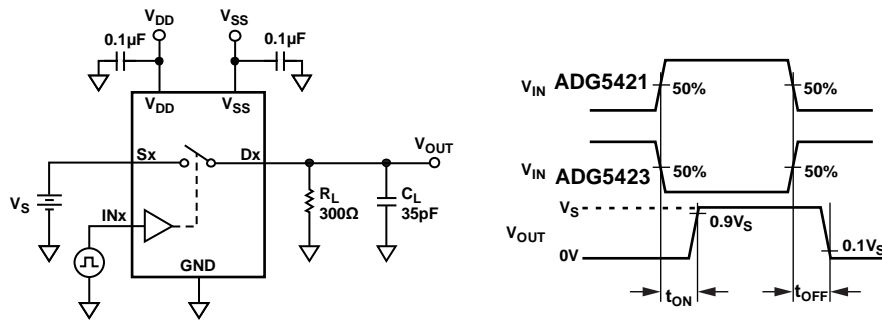


Figure 30. Switching Times, t_{ON} and t_{OFF}

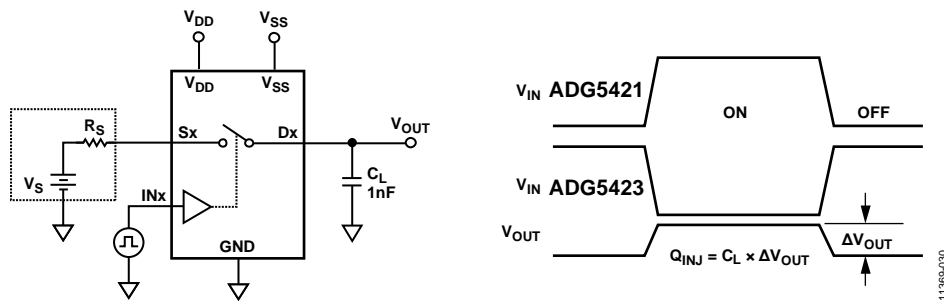


Figure 31. Charge Injection

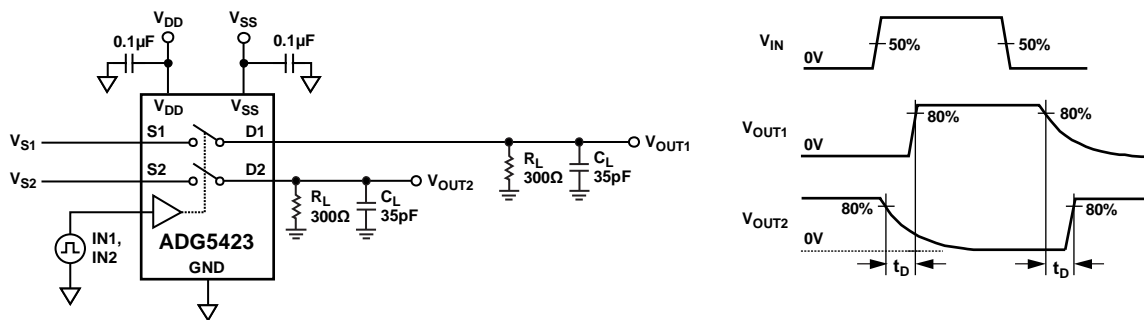


Figure 32. Break-Before-Make Time Delay

TERMINOLOGY

I_{DD}

I_{DD} represents the positive supply current.

I_{SS}

I_{SS} represents the negative supply current.

V_D, V_S

V_D and V_S represent the analog voltage on Terminal D and Terminal S, respectively.

R_{ON}

R_{ON} is the ohmic resistance between Terminal D and Terminal S.

ΔR_{ON}

ΔR_{ON} represents the difference between the R_{ON} of any two channels.

R_{FLAT (ON)}

R_{FLAT (ON)} represents the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

I_S (Off)

I_S (Off) is the source leakage current with the switch off.

I_D (Off)

I_D (Off) is the drain leakage current with the switch off.

I_D (On), I_S (On)

I_D (On) and I_S (On) represent the channel leakage currents with the switch on.

V_{INL}

V_{INL} is the maximum input voltage for Logic 0.

V_{INH}

V_{INH} is the minimum input voltage for Logic 1.

I_{INL}, I_{INH}

I_{INL} and I_{INH} represent the low and high input currents of the digital inputs.

C_D (Off)

C_D (Off) represents the off switch drain capacitance, which is measured with reference to ground.

C_S (Off)

C_S (Off) represents the off switch source capacitance, which is measured with reference to ground.

C_D (On), C_S (On)

C_D (On) and C_S (On) represent on switch capacitances, which are measured with reference to ground.

C_{IN}

C_{IN} represents digital input capacitance.

t_{ON}

t_{ON} represents the delay time between the 50% and 90% points of the digital input and switch on condition.

t_{OFF}

t_{OFF} represents the delay time between the 50% and 90% points of the digital input and switch off condition.

t_D

t_D represents the off time measured between the 80% point of both switches when switching from one address state to another.

Off Isolation

Off isolation is a measure of unwanted signal coupling through an off channel.

Charge Injection

Charge injection is a measure of the glitch impulse transferred from the digital input to the analog output during switching.

Crosstalk

Crosstalk is a measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

Bandwidth

Bandwidth is the frequency at which the output is attenuated by 3 dB from its dc level.

Total Harmonic Distortion + Noise (THD + N)

The ratio of the harmonic amplitude plus noise of the signal to the fundamental is represented by THD + N.

APPLICATIONS INFORMATION

The [ADG54xx](#) family of switches and multiplexers provide a robust solution for instrumentation, industrial, aerospace, and other harsh environments that are prone to latch-up, which is an undesirable high current state that can lead to device failure and persists until the power supply is turned off. The [ADG5421/ADG5423](#) high voltage switches allow single-supply operation from 9 V to 40 V and dual-supply operation from ± 9 V to ± 22 V. The [ADG5421/ADG5423](#) (as well as other select devices within this family) achieve an 8 kV human body model ESD rating, which provides a robust solution, eliminating the need for separate protection circuitry designs in some applications.

TRENCH ISOLATION

In the [ADG5421/ADG5423](#), an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction-isolated switches, are eliminated, and the result is a completely latch-up immune switch.

In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode can become forward-biased. The two transistors form a silicon-controlled rectifier (SCR) type circuit, causing a significant amplification of the current that, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latch-up immune switch.

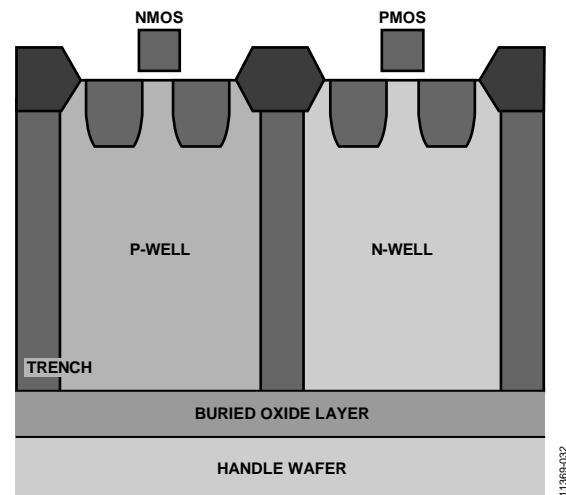


Figure 33. Trench Isolation

OUTLINE DIMENSIONS

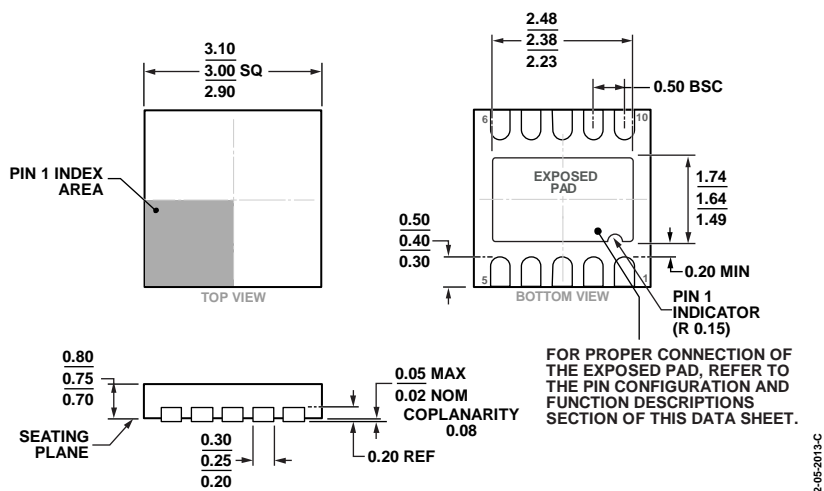
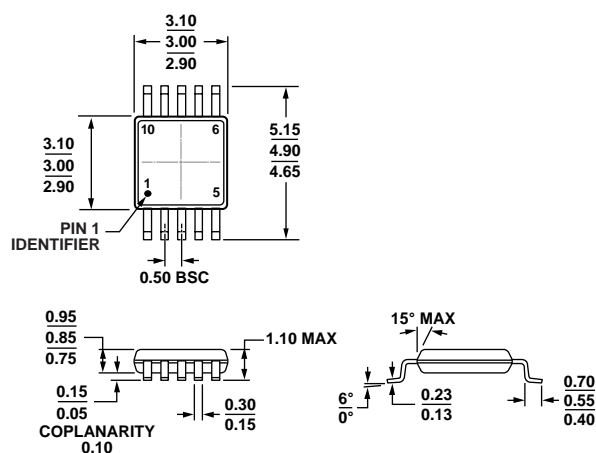


Figure 34. 10-Lead Lead Frame Chip Scale Package [LFCSP_WD]
3 mm x 3 mm Body, Very Very Thin, Dual Lead
(CP-10-9)
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-187-BA

Figure 35. 10-Lead Mini Small Outline Package [MSOP]
(RM-10)
Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Branding
ADG5421BCPZ-RL7	−40°C to +125°C	10-Lead Lead Frame Chip Scale Package [LFCSP_WD]	CP-10-9	BN
ADG5421BRMZ	−40°C to +125°C	10-Lead Mini Small Outline Package [MSOP]	RM-10	S47
ADG5421BRMZ-RL7	−40°C to +125°C	10-Lead Mini Small Outline Package [MSOP]	RM-10	S47
ADG5423BCPZ-RL7	−40°C to +125°C	10-Lead Lead Frame Chip Scale Package [LFCSP_WD]	CP-10-9	BM
ADG5423BRMZ	−40°C to +125°C	10-Lead Mini Small Outline Package [MSOP]	RM-10	S3D
ADG5423BRMZ-RL7	−40°C to +125°C	10-Lead Mini Small Outline Package [MSOP]	RM-10	S3D

¹ Z = RoHS Compliant Part.